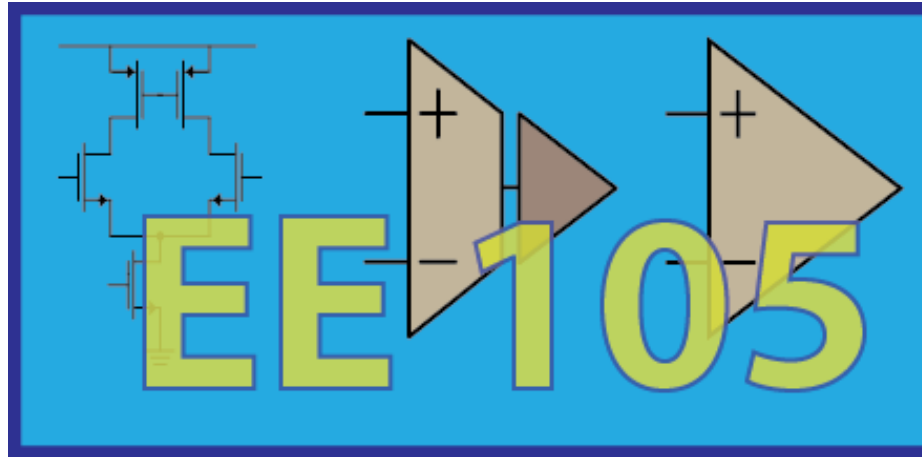




Frequency Response

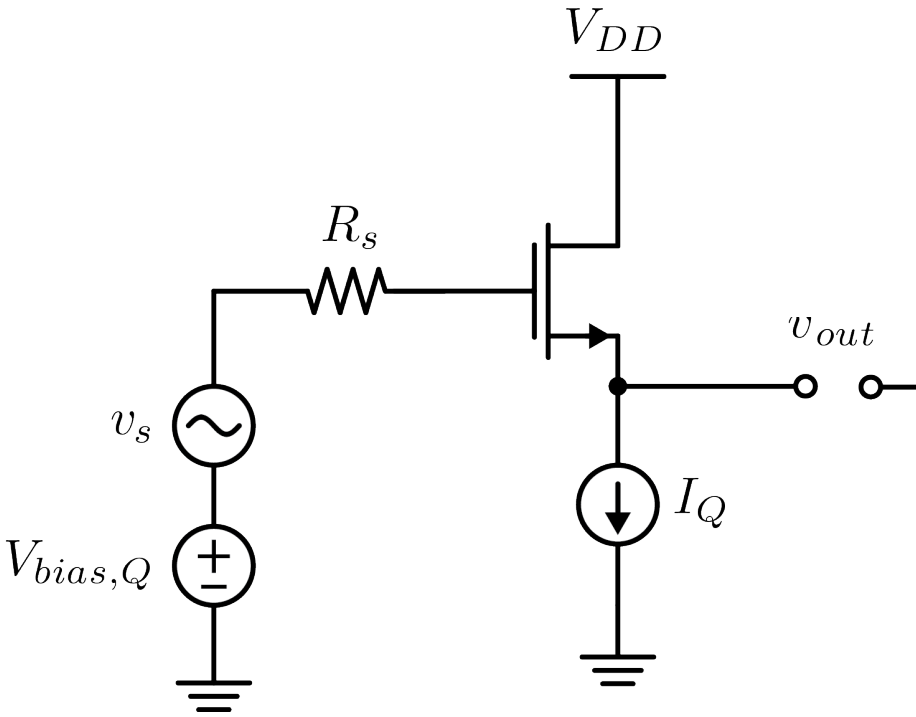
Prof. Ali M. Niknejad
Prof. Rikky Muller



Announcements

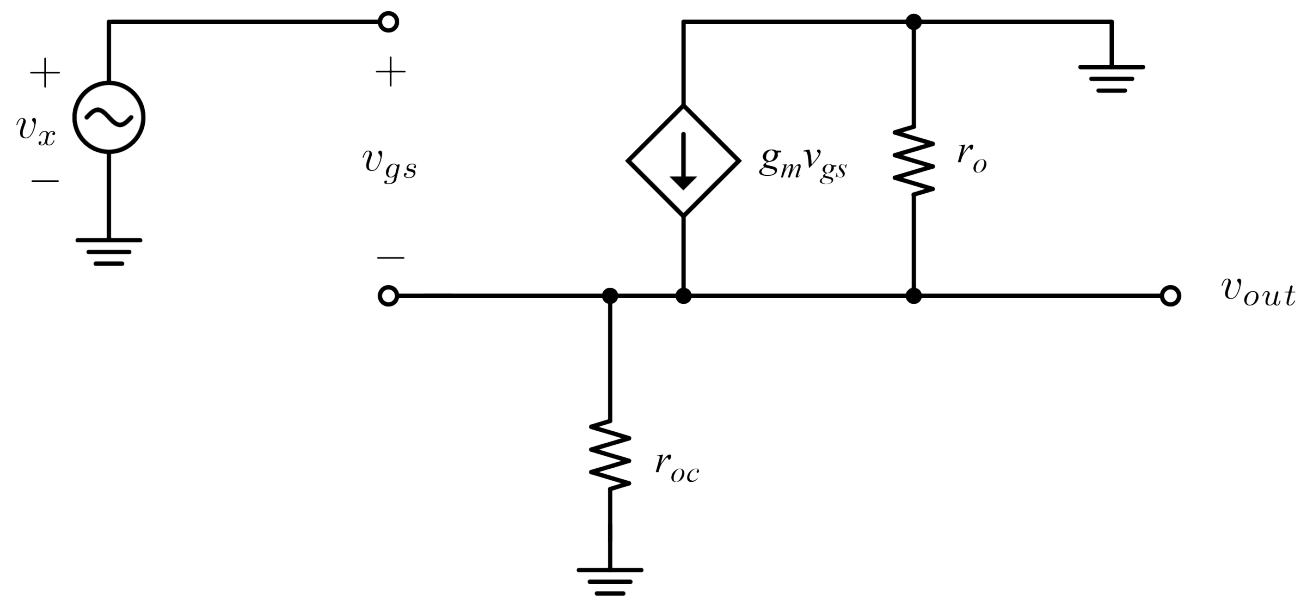
- HW9 due on Friday

Review: CD with Current Mirror

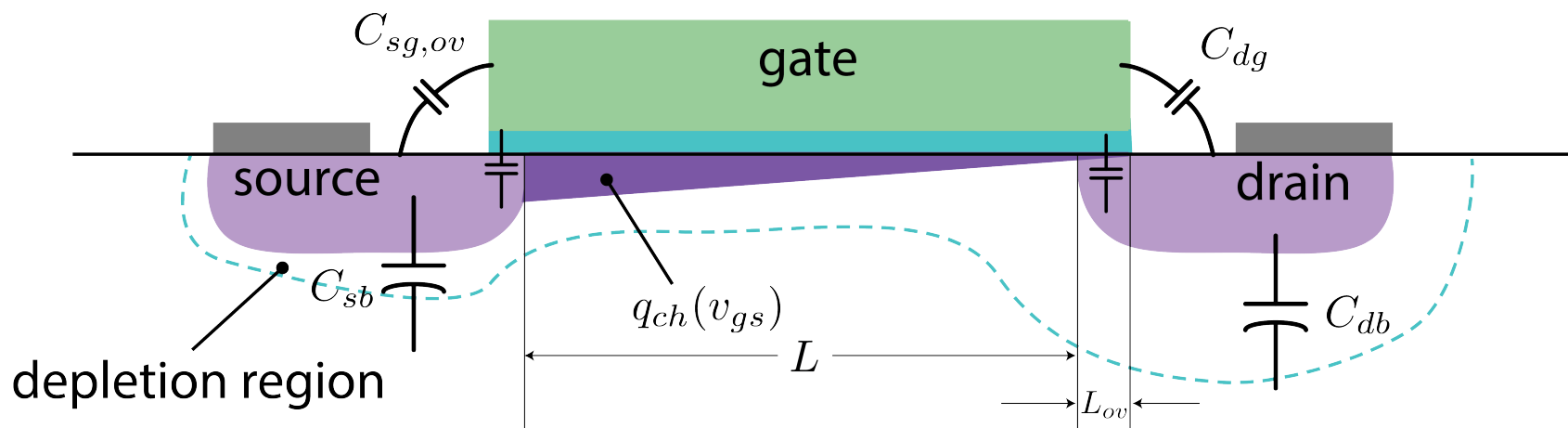


Review: CD with Current Mirror

Review: CD with Current Mirror



Capacitors in MOS Device



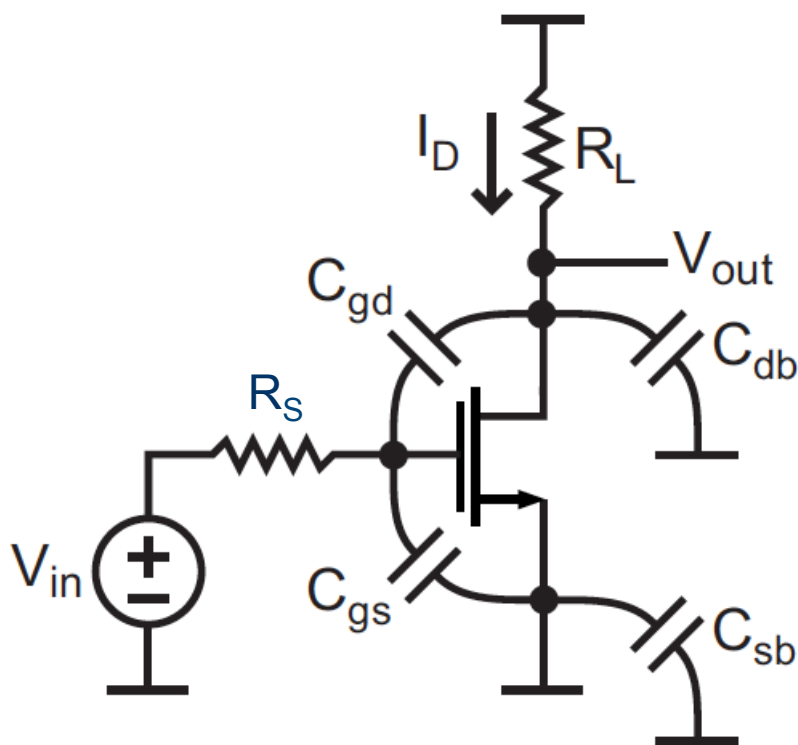
$$C_{gs} = (2/3)WLC_{ox} + C_{ov}$$

$$C_{gd} = C_{ov}$$

$$C_{sb} = C_{jsb}(\text{area} + \text{perimeter}) \text{ junction}$$

$$C_{db} = C_{jdb}(\text{area} + \text{perimeter}) \text{ junction}$$

Common-Source Voltage Amplifier



Small-signal model:

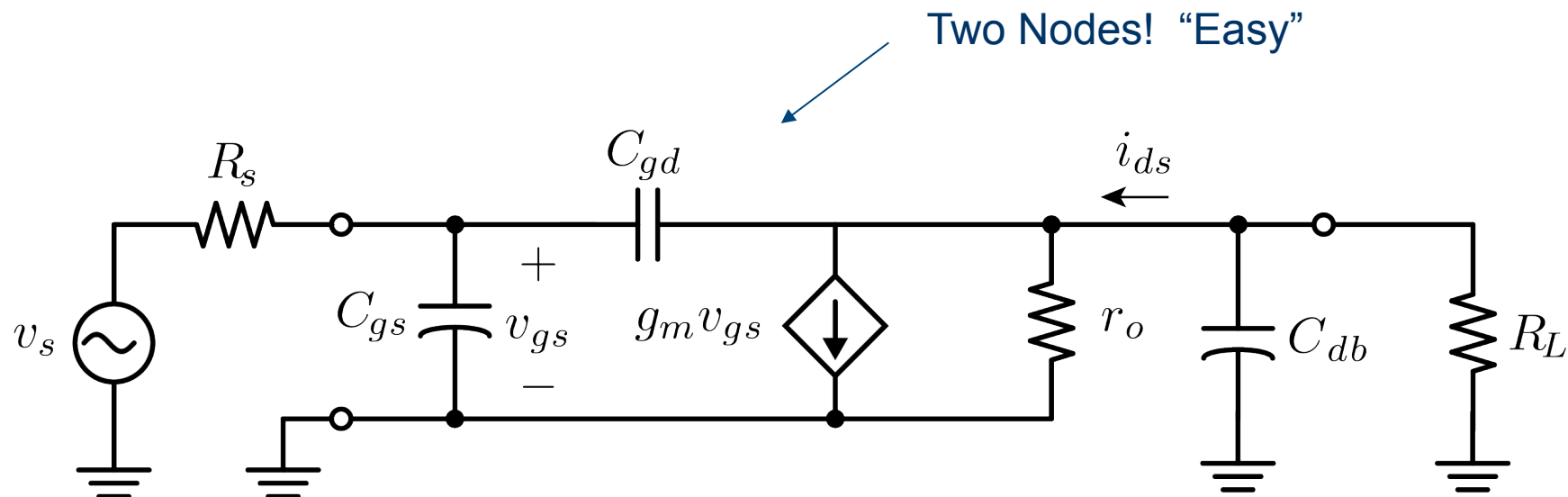
C_{sb} is connected to gnd on both sides, therefore can be ignored

Can solve problem directly by nodal analysis or using 2-port models of transistor

OK if circuit is “small” (1-2 nodes)

We can find the complete transfer function of the circuit, but in many cases it's good enough to get an estimate of the -3dB bandwidth

CS Voltage Amp Small-Signal Model



For now we will ignore C_{db} to simplify the math

Frequency Response

KCL at input and output nodes; analysis is made complicated

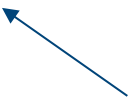
$$\frac{V_{out}}{V_{in}} = \frac{-g_m [r_o \parallel R_L] (1 - j\omega / \omega_z)}{(1 + j\omega / \omega_{p1})(1 + j\omega / \omega_{p2})}$$

Zero



Low-frequency gain:

Two Poles



$$\frac{V_{out}}{V_{in}} = \frac{-g_m [r_o \parallel R_L] (1 - j0)}{(1 + j0)(1 + j0)} \rightarrow -g_m [r_o \parallel R_L]$$



Zero:

$$\omega_z = \frac{g_m}{C_{gs} + C_{gd}}$$

Calculating the Poles

$$\omega_{p1} \approx \frac{1}{R_s \left\{ C_{gs} + (1 + g_m R'_{out}) C_{gd} \right\} + R'_{out} C_{gd}}$$

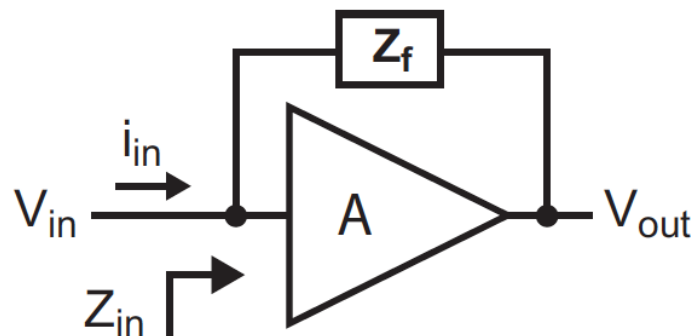
$$\omega_{p2} \approx \frac{R'_{out} / R_s}{R_s \left\{ C_{gs} + (1 + g_m R'_{out}) C_{gd} \right\} + R'_{out} C_{gd}}$$

Usually $\gg 1$

Results of complete analysis: not exact and little insight

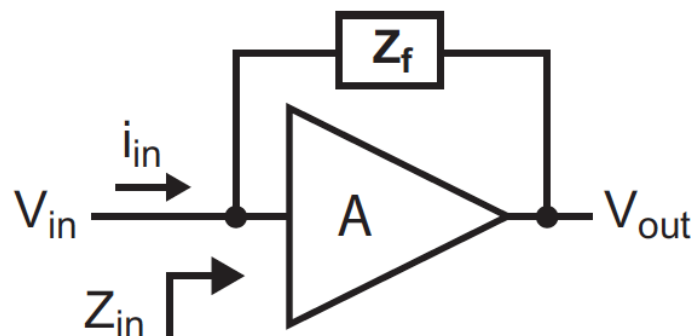
These poles are calculated after doing some algebraic manipulations on the circuit. It's hard to get any intuition from the above expressions. There must be an easier way!

Method: The Miller Effect



- Derive input impedance (assume gain of amplifier $\neq A$):

The Miller Effect



- Derive input impedance (assume gain of amplifier $\neq A$):

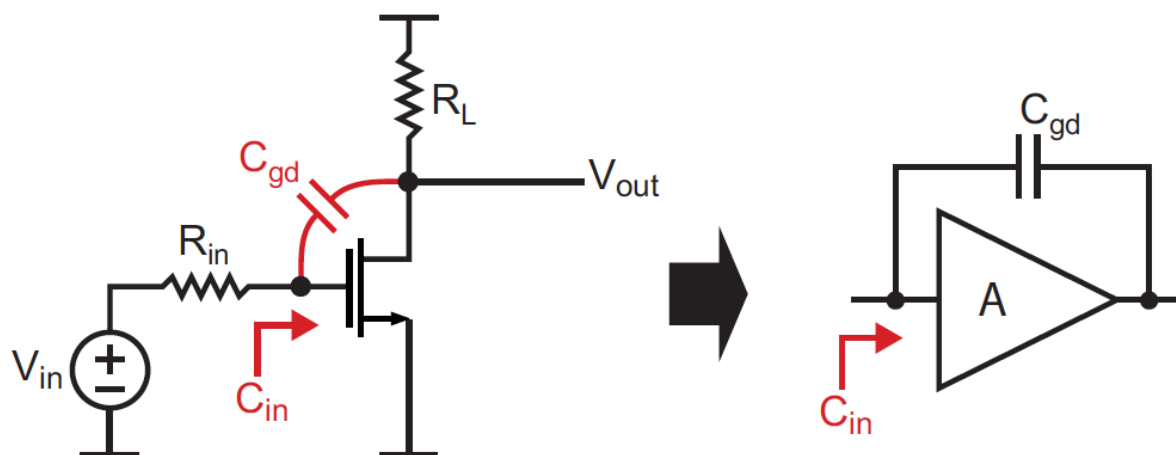
$$Z_{in} = \frac{V_{in}}{i_{in}} = \frac{V_{in}}{(V_{in} - V_{out})/Z_f} = \frac{V_{in}Z_f}{V_{in} - AV_{in}} = \frac{Z_f}{1 - A}$$

- Consider the case where Z_f is a capacitor

$$Z_f = \frac{1}{sC} \Rightarrow Z_{in} = \frac{1}{s(1 - A)C}$$

- For negative A , input impedance sees increased cap value
- For $A = 1$, input impedance sees no influence from cap
- For $A > 1$, input impedance sees negative capacitance!

Using The Miller Effect



- Notice that C_{gd} is in the feedback path of the common source amplifier

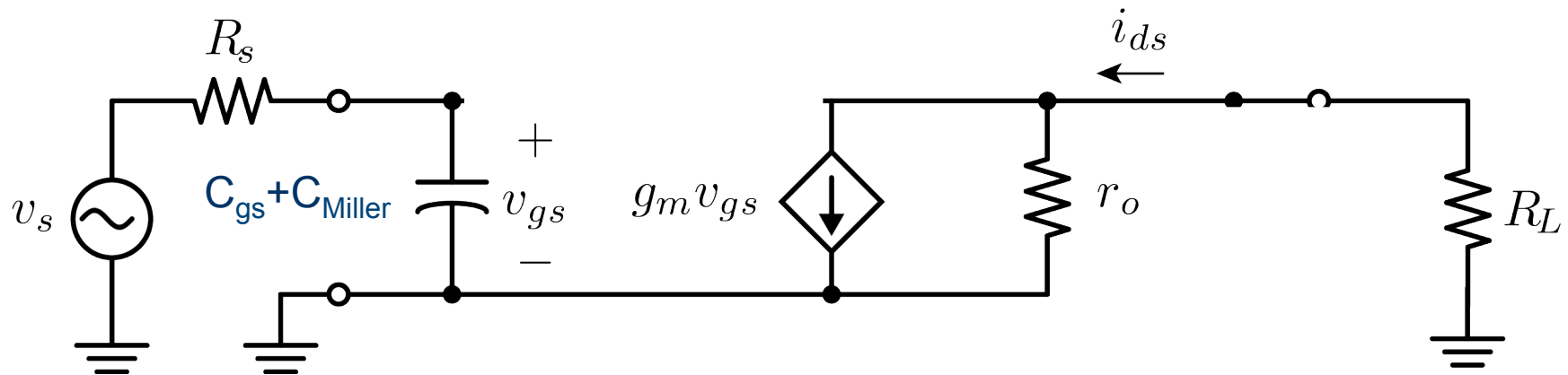
– Recall Miller effect calculation: $C_{in} = (1 - A)C_{gd}$

Effective input capacitance:

$$C_{in} = \frac{1}{j\omega C_{Miller}} = \left(\frac{1}{1 - A_{v,Cgd}} \right) \left(\frac{1}{j\omega C_{gd}} \right) = \frac{1}{j\omega \left[(1 - A_{v,Cgd}) C_{gd} \right]}$$

CS Voltage Amp Small-Signal Model

Modified Small-Signal Model with Miller Effect:



We can approximate the first pole by using Miller capacitance
This gives us a good approximation of the -3dB bandwidth

Comparison with “Exact Analysis”

Miller result (calculate RC time constant of input pole):

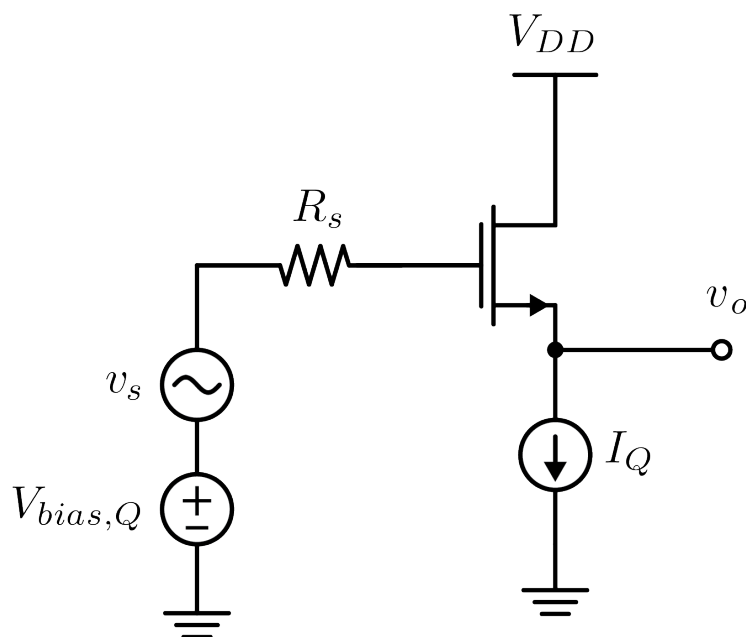
$$\omega_{p1}^{-1} = R_S \left[C_{gs} + \left(1 + g_m R'_{out} \right) C_{gd} \right]$$

Exact result:

$$\omega_{p1}^{-1} = R_S \left[C_{gs} + \left(1 + g_m R'_{out} \right) C_{gd} \right] + R'_{out} C_{gd}$$

As a result of the Miller effect there is a fundamental gain-bandwidth tradeoff

Common Drain Amplifier

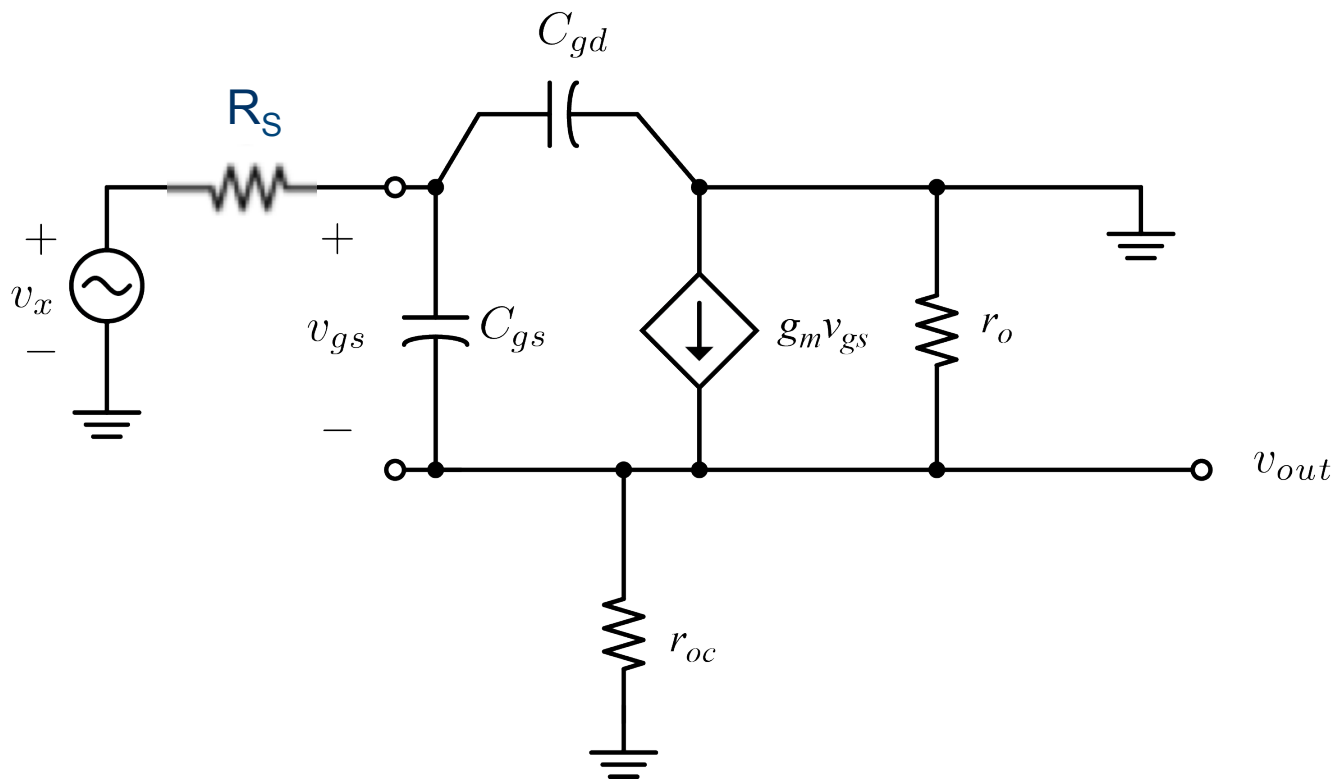


Calculate Bandwidth of the
Common Drain (Source-
Follower)

Procedure:

1. Replace current source with MOSFET-based current mirror
2. Draw small-signal model with capacitors (for simplicity, we will focus on C_{gd} and C_{gs})
3. Find the DC small-signal gain
4. Use the Miller effect to calculate the input capacitance
5. Calculate the dominant pole

Two-Port CC Model with Capacitors



-Find DC Gain

-Find Miller capacitor for C_{gs} -- *note that the gate-source capacitor is between the input and output!*

Voltage Gain Across C_{gs}

Write KCL at output node:

$$\frac{v_{out}}{r_o \parallel r_{oc}} = g_m v_{gs} = g_m (v_{in} - v_{out})$$

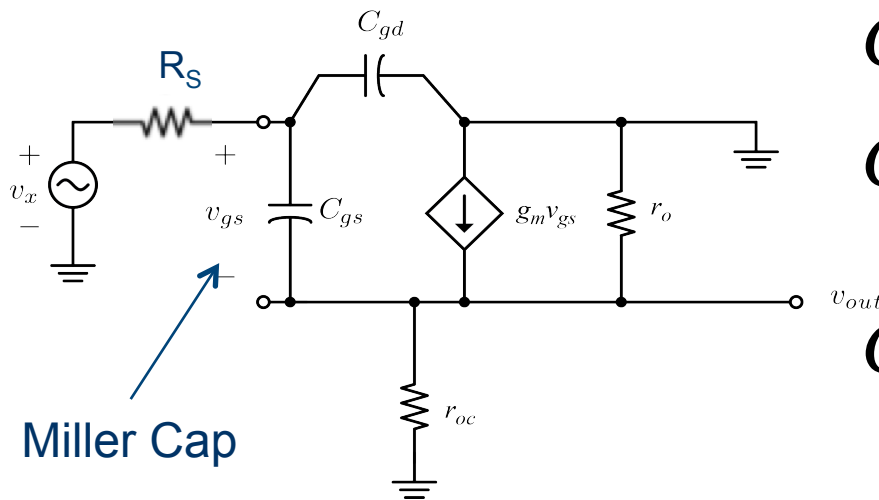
$$v_{out} \left(\frac{1}{r_o \parallel r_{oc}} + g_m \right) = g_m v_{in}$$

$$\frac{v_{out}}{v_{in}} = \frac{g_m}{\left(\frac{1}{r_o \parallel r_{oc}} + g_m \right)} = \frac{g_m (r_o \parallel r_{oc})}{1 + g_m (r_o \parallel r_{oc})} = A_{vC_{gs}}$$

Compute Miller Effected Capacitance

Now use the Miller Effect to compute C_{in} :

Remember that C_{gs} is the capacitor from the input to the output



$$C_{in} = C_{gd} + C_M$$

$$C_{in} = C_{gd} + (1 - A_v C_{gs}) C_{gs}$$

$$C_{in} = C_{gd} + \left(1 - \frac{g_m (r_o \parallel r_{oc})}{1 + g_m (r_o \parallel r_{oc})}\right) C_{gs}$$

$$C_{in} = C_{gd} + \left(\frac{1}{1 + g_m (r_o \parallel r_{oc})}\right) C_{gs}$$

$$C_{in} \approx C_{gd}$$

(for large $g_m (r_o \parallel r_{oc})$)

Bandwidth of Source Follower

Input low-pass filter's -3 dB frequency:

$$\omega_p^{-1} = R_S \left(C_{gd} + \frac{C_{gs}}{1 + g_m(r_o \parallel r_{oc})} \right)$$

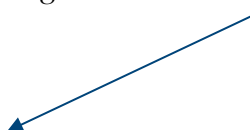
Substitute favorable values of R_S , r_o :

$$R_S \approx 1 / g_m \quad r_o \gg 1 / g_m$$

$$\omega_p^{-1} \approx (1 / g_m) \left(C_{gd} + \frac{C_{gs}}{1 + \text{BIG}} \right) \approx C_{gd} / g_m$$

$$\omega_p \approx g_m / C_{gd}$$

Very high frequency!
Model not valid at
these high frequencies



Some Examples

Common source amplifier:

$$A_{vC_{gd}} = \text{Negative, large number } (-100)$$

$$C_{Miller} = (1 - A_{V,C_{gd}})C_{gd} \approx 100C_{gd}$$

Miller Multiplied Cap has detrimental impact on bandwidth

Common drain amplifier:

$$A_{vC_{gs}} = \text{Slightly less than } 1$$

$$C_{Miller} = (1 - A_{V,C_{gs}})C_{gs} \simeq 0$$

“Bootstrapped” cap has negligible impact on bandwidth!